

## High Voltage IGBT For Capacitor Discharge Applications

### (Electrically Isolated Tab)

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Symbol	lest Conditions	Maximum F	latings
V <sub>ces</sub>	$T_{J} = 25^{\circ}C \text{ to } 150^{\circ}C$	3000	V
V <sub>cgr</sub>	$T_{_J}$ = 25°C to 150°C, $R_{_{GE}}$ = 1M $\Omega$	3000	V
V <sub>GES</sub>	Continuous	± 20	V
V <sub>gem</sub>	Transient	± 30	V
I <sub>C25</sub>	$T_c = 25^{\circ}C$	27	A
I <sub>C90</sub>	$T_{c} = 90^{\circ}C$	16	A
I <sub>см</sub>	$T_{_{\rm C}}$ = 25°C, $V_{_{\rm GE}}$ = 20V, 1ms	140	А
SSOA	$V_{GE}$ = 20V, $T_{VJ}$ = 125°C, $R_{G}$ = 5 $\Omega$	I <sub>CM</sub> = 160	A
(RBSOA)	Clamped Inductive Load	$V_{_{CE}} \leq 0.8 \bullet V_{_{CES}}$	
P <sub>c</sub>	$T_c = 25^{\circ}C$	114	W
T		-55 +150	°C
T <sub>JM</sub>		150	°C
T <sub>stg</sub>		-55 +150	°C
T <sub>L</sub> T <sub>SOLD</sub>	1.6 mm (0.062 in.) from Case for 10s Plastic Body for 10s	300 260	⊃° ⊃°
F <sub>c</sub>	Mounting Force	20120/4.527	Nm/lb-in.
VISOL	50/60Hz, 1 Minute	4000	٧~
Weight		5	g

Symbol	Test Conditions	Chara	Characteristic Values		
$(T_J = 25^{\circ}C)$	C, Unless Otherwise Specified)	Min.	Тур.	Ma	х.
BV <sub>CES</sub>	$I_{c}$ = 1mA, $V_{GE}$ = 0V	3000			V
V <sub>GE(th)</sub>	$I_{c}$ = 250 $\mu$ A, $V_{ce}$ = $V_{ge}$	3.0		5.0	V
I <sub>CES</sub>	$V_{CE} = 0.8 \bullet V_{CES}, V_{GE} = 0V$ Note 2, $T_{J}$ :	= 125°C		50 1	μA mA
I <sub>GES</sub>	$V_{CE} = 0V, V_{GE} = \pm 20V$			±100	nA
V <sub>CE(sat)</sub>	$I_{c} = 25A, V_{GE} = 15V, Note 1$ $I_{c} = 75A$			3.0 5.5	V

#### ISOPLUS i4-Pak<sup>™</sup>



1 = Gate 2 = Emitter

5 = Collector

#### Features

- Silicon Chip on Direct-Copper Bond (DCB) Substrate
- Isolated Mounting Surface
- 4000V Electrical Isolation
- High Peak Current Capability
- Low Saturation Voltage
- Molding Epoxies Meet UL 94 V-0 Flammability Classification

#### Applications

- Capacitor Discharge
- Pulser Circuits

#### Advantages

- High Power Density
- Easy to Mount

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# IXGF25N300

<b>Symbol Test Conditions</b> (T <sub>J</sub> = 25°C, Unless Otherwise Specified)		Characteristic Values Min.			
<b>g</b> <sub>fs</sub>		$I_{c} = 50A, V_{ce} = 10V, Note 1$	16	26	S
I <sub>C(ON)</sub>		$V_{ge} = 15V, V_{ce} = 20V, Note 1$		240	A
C <sub>ies</sub>	)			2970	pF
$\mathbf{C}_{\text{oes}}$	}	$V_{_{CE}}$ = 15V, $V_{_{GE}}$ = 20V, f = 1MHz		98	pF
$\mathbf{C}_{res}$	J			36	pF
Q <sub>a(on)</sub>	١			75	nC
Q <sub>ge</sub>	}	$I_{_{\mathrm{C}}} = 50$ A, $V_{_{\mathrm{GE}}} = 15$ V, $V_{_{\mathrm{CE}}} = 0.5 \bullet V_{_{\mathrm{CES}}}$		15	nC
Q <sub>gc</sub>	J			30	nC
t <sub>d(on)</sub>	١	Resistive Switching Times		70	ns
t,		$  -254 \rangle V - 15V$		240	ns
t <sub>d(off)</sub>		V = 1500V B = 50		220	ns
t <sub>f</sub>	J	$C_{CE} = 100000$ , $H_{G} = 0000$		500	ns
R <sub>th-IC</sub>					1.10 °C/W
R <sub>thCS</sub> R <sub>thJA</sub>				0.15 30	°C/W °C/W



SYM	INCH	INCHES MILLIMETE		ETERS	
	MIN	MAX	MIN	MAX	
Α	.190	.205	4.83	5.21	
A1	.102	.118	2.59	3.00	
A2	.046	.085	1.17	2.16	
b	.045	.055	1.14	1.40	
b1	.058	.068	1.47	1.73	
С	.020	.029	0.51	0.74	
D	.819	.840	20.80	21.34	
E	.770	.799	19.56	20.29	
е	.150 BSC		3.81 BSC		
e1	.450BSC		11.43	3 BSC	
L	.780	.840	19.81	21.34	
L1	.083	.102	2.11	2.59	
Q	.210	.244	5.33	6.20	
R	.100	.180	2.54	4.57	
S	.660	.690	16.76	17.53	
Т	.590	.620	14.99	15.75	
U	.065	.080	1.65	2.03	

#### Notes:

- 1. Pulse test, t < 300 $\mu$ s, duty cycle, d < 2%.
- 2. Device must be heatsunk for high-temperature leakage current measurements to avoid thermal runaway.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



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